

MRFG35003NT1 replaced by MRFG35003ANT1.

Gallium Arsenide PHEMT

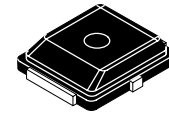
RF Power Field Effect Transistor

Designed for WLL/MMDS/BWA or UMTS driver applications with frequencies from 1.8 to 3.6 GHz. Device is unmatched and is suitable for use in Class AB linear base station applications.

- Typical W-CDMA Performance: -42 dBc ACPR, 3.55 GHz, 12 Volts, $I_{DQ} = 55$ mA, 5 MHz Offset/3.84 MHz BW, 64 DPCH (8.5 dB P/A @ 0.01% Probability)
 Output Power — 300 mWatt
 Power Gain — 11.5 dB
 Efficiency — 25%
- 3 Watts P1dB @ 3.55 GHz
- Excellent Phase Linearity and Group Delay Characteristics
- High Gain, High Efficiency and High Linearity
- N Suffix Indicates Lead-Free Terminations. RoHS Compliant.
- In Tape and Reel. T1 Suffix = 1000 Units per 12 mm, 7 inch Reel.

MRFG35003NT1

**3.5 GHz, 3 W, 12 V
 POWER FET
 GaAs PHEMT**



**CASE 466-03, STYLE 1
 PLD-1.5
 PLASTIC**

ARCHIVE INFORMATION

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Table 1. Maximum Ratings

| Rating | Symbol | Value | Unit |
|--|-----------|---------------------|--------------------------|
| Drain-Source Voltage | V_{DSS} | 15 | Vdc |
| Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C | P_D | 8.1 (2) 0.05 (2) | W W/ $^\circ\text{C}$ |
| Gate-Source Voltage | V_{GS} | -5 | Vdc |
| RF Input Power | P_{in} | 29 | dBm |
| Storage Temperature Range | T_{stg} | -65 to +150 | $^\circ\text{C}$ |
| Channel Temperature (1) | T_{ch} | 175 | $^\circ\text{C}$ |
| Operating Case Temperature Range | T_C | -20 to +85 | $^\circ\text{C}$ |

Table 2. Thermal Characteristics

| Characteristic | Symbol | Value | Unit |
|--|-----------------|----------|---------------------------|
| Thermal Resistance, Junction to Case Class AB | $R_{\theta JC}$ | 18.5 (2) | $^\circ\text{C}/\text{W}$ |

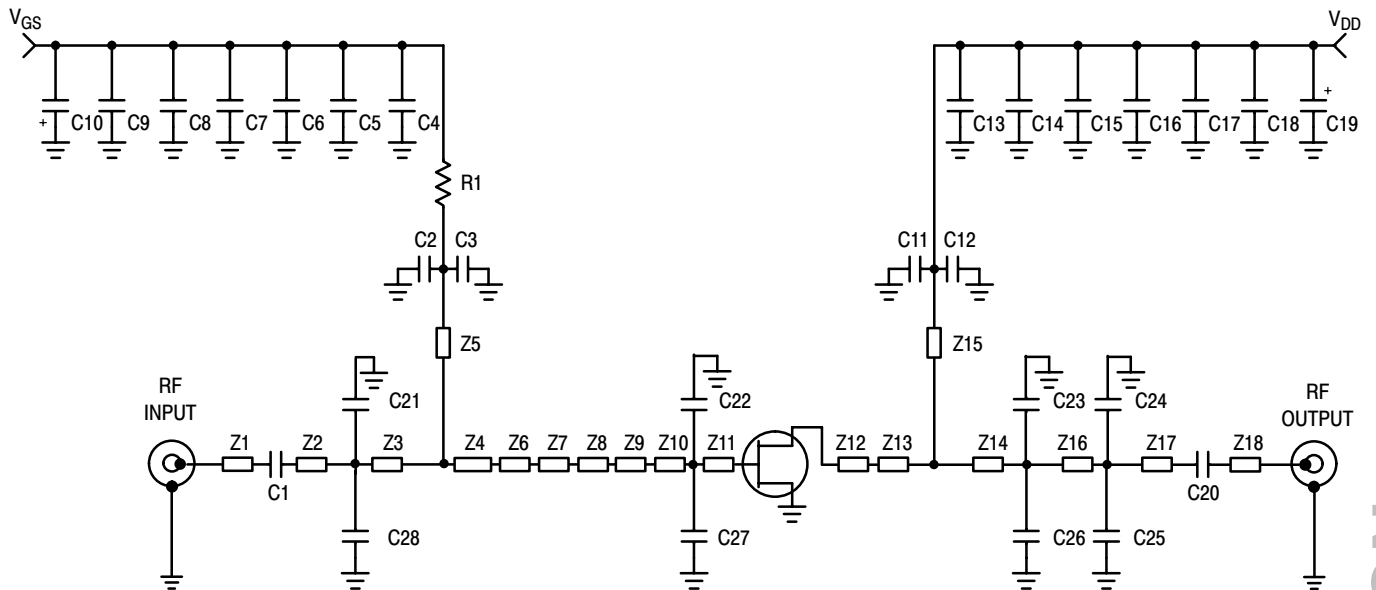
Table 3. Moisture Sensitivity Level

| Test Methodology | Rating | Package Peak Temperature | Unit |
|---------------------------------------|--------|--------------------------|------------------|
| Per JESD 22-A113, IPC/JEDEC J-STD-020 | 1 | 260 | $^\circ\text{C}$ |

1. For reliable operation, the operating channel temperature should not exceed 150°C .
2. Simulated.

Table 4. Electrical Characteristics ($T_C = 25^\circ\text{C}$ unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|--|--------------|------|-------|------|-----------------|
| Saturated Drain Current ($V_{DS} = 3.5 \text{ Vdc}$, $V_{GS} = 0 \text{ Vdc}$) | I_{DSS} | — | 1.3 | — | Adc |
| Off State Leakage Current ($V_{GS} = -0.4 \text{ Vdc}$, $V_{DS} = 0 \text{ Vdc}$) | I_{GSS} | — | < 1.0 | 100 | μAdc |
| Off State Drain Current ($V_{DS} = 12 \text{ Vdc}$, $V_{GS} = -2.5 \text{ Vdc}$) | I_{DSO} | — | — | 450 | μAdc |
| Off State Current ($V_{DS} = 28.5 \text{ Vdc}$, $V_{GS} = -2.5 \text{ Vdc}$) | I_{DSX} | — | < 1.0 | 7 | mAdc |
| Gate-Source Cut-off Voltage ($V_{DS} = 3.5 \text{ Vdc}$, $I_{DS} = 6.5 \text{ mA}$) | $V_{GS(th)}$ | -1.2 | -0.9 | -0.7 | Vdc |
| Quiescent Gate Voltage ($V_{DS} = 12 \text{ Vdc}$, $I_D = 55 \text{ mA}$) | $V_{GS(Q)}$ | -1.2 | -0.9 | -0.7 | Vdc |
| Power Gain ($V_{DD} = 12 \text{ Vdc}$, $I_{DQ} = 55 \text{ mA}$, $f = 3.55 \text{ GHz}$) | G_{ps} | 10 | 11.5 | — | dB |
| Output Power, 1 dB Compression Point ($V_{DD} = 12 \text{ Vdc}$, $I_{DQ} = 55 \text{ mA}$, $f = 3.55 \text{ GHz}$) | P_{1dB} | — | 3 | — | W |
| Drain Efficiency ($V_{DD} = 12 \text{ Vdc}$, $I_{DQ} = 55 \text{ mA}$, $P_{out} = 0.30 \text{ W Avg.}$, $f = 3.55 \text{ GHz}$) | η_D | 23 | 25 | — | % |
| Adjacent Channel Power Ratio ($V_{DD} = 12 \text{ Vdc}$, $P_{out} = 0.30 \text{ W Avg.}$, $I_{DQ} = 55 \text{ mA}$, $f = 3.55 \text{ GHz}$, W-CDMA, 8.5 P/A @ 0.01% Probability, 64 CH, 3.84 MCPS) | ACPR | — | -42 | -40 | dBc |

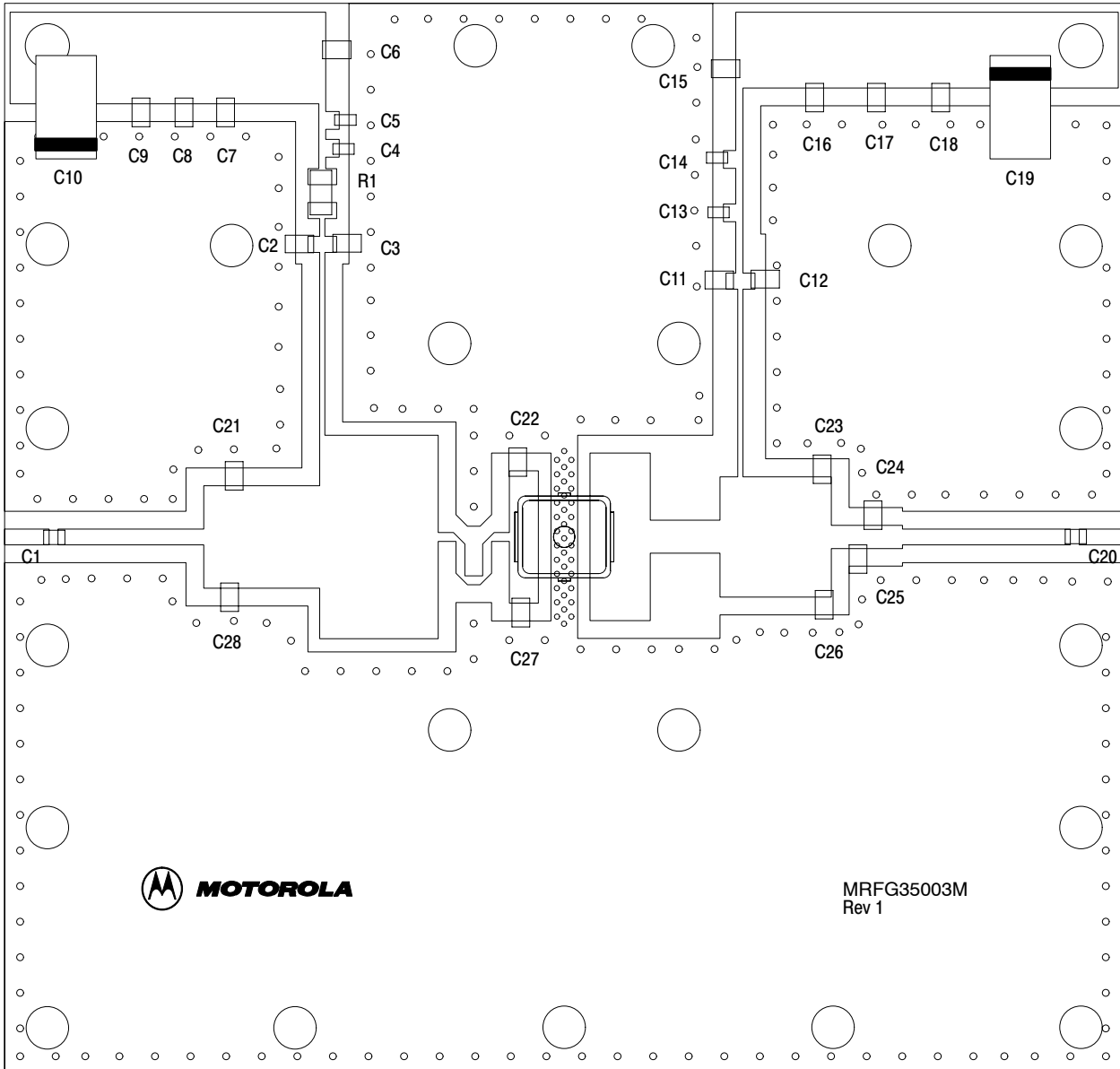


| | | | |
|-------------|----------------------------|-----|---|
| Z1, Z18 | 0.125" x 0.044" Microstrip | Z11 | 0.082" x 0.372" Microstrip |
| Z2 | 0.409" x 0.044" Microstrip | Z12 | 0.169" x 0.471" Microstrip |
| Z3 | 0.326" x 0.288" Microstrip | Z13 | 0.196" x 0.093" Microstrip |
| Z4 | 0.333" x 0.572" Microstrip | Z14 | 0.313" x 0.338" Microstrip |
| Z5, Z15 | 0.527" x 0.015" Microstrip | Z16 | 0.200" x 0.065" Microstrip |
| Z6, Z8, Z10 | 0.050" x 0.025" Microstrip | Z17 | 0.472" x 0.044" Microstrip |
| Z7, Z9 | 0.097" x 0.025" Microstrip | PCB | Rogers 4350, 0.020", $\epsilon_r = 3.5$ |

Figure 1. 3.5 GHz Test Circuit Schematic

Table 5. 3.5 GHz Test Circuit Component Designations and Values

| Part | Description | Part Number | Manufacturer |
|------------------|--|---------------|--------------|
| C1, C20 | 7.5 pF Chip Capacitors | 100A7R5JP150X | ATC |
| C2, C3, C11, C12 | 3.9 pF Chip Capacitors (0805) | 08051J3R9BBT | AVX |
| C4, C13 | 10 pF Chip Capacitors | 100A100JP500X | ATC |
| C5, C14 | 100 pF Chip Capacitors | 100A101JP500X | ATC |
| C6, C15 | 100 pF Chip Capacitors | 100B101JP500X | ATC |
| C7, C16 | 1000 pF Chip Capacitors | 100B102JP500X | ATC |
| C8, C17 | 3.9 μ F Chip Capacitors | | ATC |
| C9, C18 | 0.1 μ F Chip Capacitors | | ATC |
| C10, C19 | 22 μ F, 35 V Tantalum Surface Mount Capacitors | | ATC |
| C21 | 0.7 pF Chip Capacitor (0805) | 08051J0R7BBT | AVX |
| C22, C27 | 0.2 pF Chip Capacitors (0805) | 08051J0R2BBT | AVX |
| C23, C28 | 0.8 pF Chip Capacitors (0805) | 08051J0R8BBT | AVX |
| C24 | 1.0 pF Chip Capacitor | 08051J1R0BBT | AVX |
| C25 | 1.2 pF Chip Capacitor | 08051J1R2BBT | AVX |
| C26 | 0.5 pF Chip Capacitor | 08051J0R5BBT | AVX |
| R1 | 100 Ω Chip Resistor | | Newark |



Freescale has begun the transition of marking Printed Circuit Boards (PCBs) with the Freescale Semiconductor signature/logo. PCBs may have either Motorola or Freescale markings during the transition period. These changes will have no impact on form, fit or function of the current product.

Figure 2. 3.5 GHz Test Circuit Component Layout

TYPICAL CHARACTERISTICS

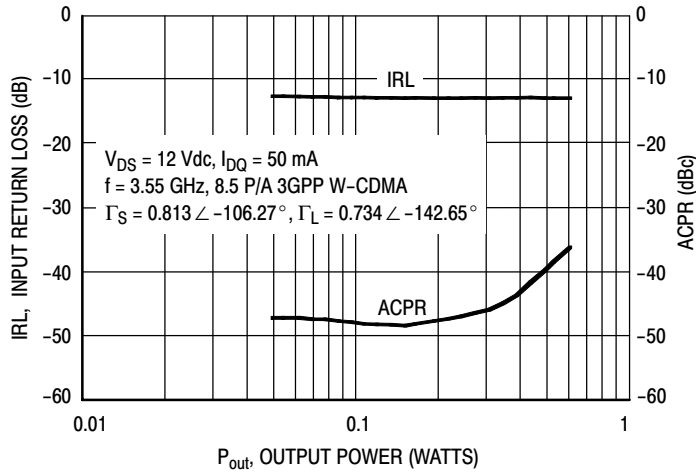


Figure 3. W-CDMA ACPR and Input Return Loss versus Output Power

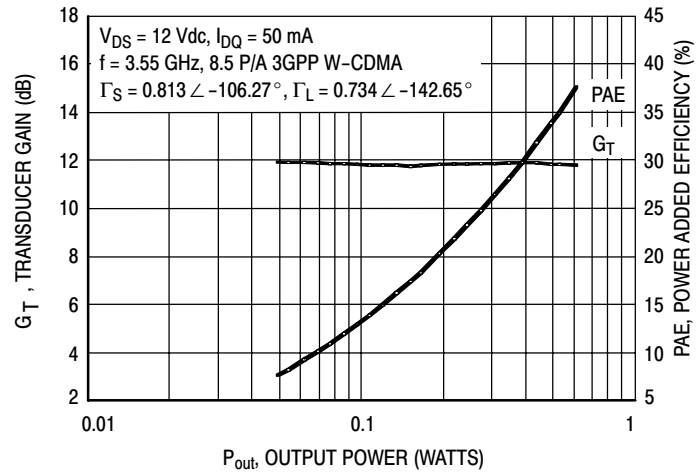


Figure 4. Transducer Gain and Power Added Efficiency versus Output Power

NOTE: All data is referenced to package lead interface. Γ_S and Γ_L are the impedances presented to the DUT. All data is generated from load pull, not from the test circuit shown.

Table 6. Class AB Common Source S-Parameters at $V_{DS} = 12$ Vdc, $I_{DQ} = 50$ mA

| f GHz | S ₁₁ | | S ₂₁ | | S ₁₂ | | S ₂₂ | |
|----------|-----------------|---------|-----------------|-------|-----------------|--------|-----------------|---------|
| | S ₁₁ | ∠φ | S ₂₁ | ∠φ | S ₁₂ | ∠φ | S ₂₂ | ∠φ |
| 0.50 | 0.879 | -160.58 | 8.644 | 88.22 | 0.038 | 6.94 | 0.520 | -161.47 |
| 0.55 | 0.879 | -163.33 | 7.924 | 85.88 | 0.039 | 5.42 | 0.520 | -163.29 |
| 0.60 | 0.877 | -166.03 | 7.317 | 83.57 | 0.039 | 3.80 | 0.520 | -165.21 |
| 0.65 | 0.876 | -168.54 | 6.811 | 81.29 | 0.039 | 2.37 | 0.520 | -167.01 |
| 0.70 | 0.877 | -170.64 | 6.380 | 79.13 | 0.039 | 0.94 | 0.521 | -168.58 |
| 0.75 | 0.875 | -172.68 | 5.988 | 77.06 | 0.039 | -0.41 | 0.520 | -170.13 |
| 0.80 | 0.877 | -174.56 | 5.653 | 75.00 | 0.040 | -1.67 | 0.520 | -171.60 |
| 0.85 | 0.876 | -176.25 | 5.310 | 72.83 | 0.040 | -2.81 | 0.520 | -172.89 |
| 0.90 | 0.874 | -177.90 | 5.058 | 71.00 | 0.040 | -4.01 | 0.519 | -174.37 |
| 0.95 | 0.875 | -179.54 | 4.825 | 69.08 | 0.040 | -5.15 | 0.520 | -175.84 |
| 1.00 | 0.876 | 179.00 | 4.608 | 67.27 | 0.040 | -6.31 | 0.520 | -177.05 |
| 1.05 | 0.875 | 177.53 | 4.411 | 65.38 | 0.040 | -7.28 | 0.519 | -178.37 |
| 1.10 | 0.874 | 176.04 | 4.224 | 63.51 | 0.040 | -8.43 | 0.520 | -179.67 |
| 1.15 | 0.875 | 174.55 | 4.056 | 61.69 | 0.040 | -9.47 | 0.521 | 179.15 |
| 1.20 | 0.874 | 173.13 | 3.894 | 59.88 | 0.040 | -10.47 | 0.520 | 177.91 |
| 1.25 | 0.873 | 171.63 | 3.743 | 58.01 | 0.040 | -11.78 | 0.521 | 176.52 |
| 1.30 | 0.876 | 170.20 | 3.609 | 56.26 | 0.040 | -12.79 | 0.522 | 175.56 |
| 1.35 | 0.871 | 168.97 | 3.479 | 54.57 | 0.040 | -13.72 | 0.520 | 174.80 |
| 1.40 | 0.878 | 167.17 | 3.355 | 52.76 | 0.040 | -14.65 | 0.526 | 173.34 |
| 1.45 | 0.876 | 165.98 | 3.237 | 51.14 | 0.040 | -15.48 | 0.526 | 172.88 |
| 1.50 | 0.874 | 162.45 | 3.118 | 49.25 | 0.040 | -16.80 | 0.528 | 174.64 |
| 1.55 | 0.874 | 161.17 | 3.024 | 47.67 | 0.040 | -17.76 | 0.529 | 173.65 |
| 1.60 | 0.874 | 160.09 | 2.929 | 46.14 | 0.040 | -18.51 | 0.530 | 172.88 |
| 1.65 | 0.876 | 159.00 | 2.848 | 44.54 | 0.040 | -19.27 | 0.530 | 172.31 |
| 1.70 | 0.878 | 157.85 | 2.767 | 42.99 | 0.039 | -20.03 | 0.531 | 171.29 |
| 1.75 | 0.878 | 156.84 | 2.690 | 41.32 | 0.039 | -20.89 | 0.533 | 170.58 |
| 1.80 | 0.878 | 155.94 | 2.625 | 39.82 | 0.039 | -21.53 | 0.533 | 170.03 |
| 1.85 | 0.880 | 154.93 | 2.557 | 38.21 | 0.039 | -22.22 | 0.533 | 168.95 |
| 1.90 | 0.879 | 154.05 | 2.492 | 36.74 | 0.039 | -23.01 | 0.536 | 168.19 |
| 1.95 | 0.879 | 153.24 | 2.434 | 35.28 | 0.039 | -23.74 | 0.535 | 167.63 |
| 2.00 | 0.881 | 152.32 | 2.379 | 33.68 | 0.039 | -24.55 | 0.535 | 166.68 |
| 2.05 | 0.881 | 151.56 | 2.325 | 32.27 | 0.040 | -25.32 | 0.538 | 165.91 |
| 2.10 | 0.880 | 150.85 | 2.279 | 30.90 | 0.040 | -25.97 | 0.539 | 165.46 |
| 2.15 | 0.881 | 149.96 | 2.236 | 29.41 | 0.040 | -26.76 | 0.537 | 164.56 |
| 2.20 | 0.881 | 149.27 | 2.191 | 27.93 | 0.040 | -27.75 | 0.539 | 163.66 |
| 2.25 | 0.880 | 148.61 | 2.151 | 26.53 | 0.040 | -28.56 | 0.541 | 163.24 |
| 2.30 | 0.880 | 147.74 | 2.121 | 24.99 | 0.040 | -29.32 | 0.539 | 162.46 |
| 2.35 | 0.881 | 146.91 | 2.084 | 23.54 | 0.040 | -29.95 | 0.539 | 161.41 |
| 2.40 | 0.879 | 146.12 | 2.051 | 22.12 | 0.040 | -30.72 | 0.540 | 160.97 |
| 2.45 | 0.877 | 145.07 | 2.023 | 20.46 | 0.040 | -31.44 | 0.539 | 160.26 |
| 2.50 | 0.876 | 144.07 | 1.992 | 18.93 | 0.040 | -32.36 | 0.539 | 159.16 |
| 2.55 | 0.876 | 143.15 | 1.971 | 17.38 | 0.040 | -32.95 | 0.541 | 158.56 |
| 2.60 | 0.873 | 142.10 | 1.948 | 15.95 | 0.041 | -33.58 | 0.538 | 157.90 |
| 2.65 | 0.872 | 140.88 | 1.924 | 14.31 | 0.041 | -34.41 | 0.538 | 156.83 |
| 2.70 | 0.872 | 139.83 | 1.901 | 12.69 | 0.041 | -35.22 | 0.538 | 156.16 |
| 2.75 | 0.867 | 138.60 | 1.882 | 11.19 | 0.042 | -36.04 | 0.537 | 155.70 |
| 2.80 | 0.868 | 137.26 | 1.864 | 9.40 | 0.042 | -37.16 | 0.535 | 154.59 |

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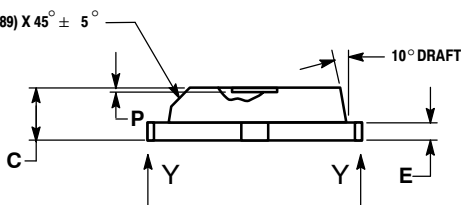
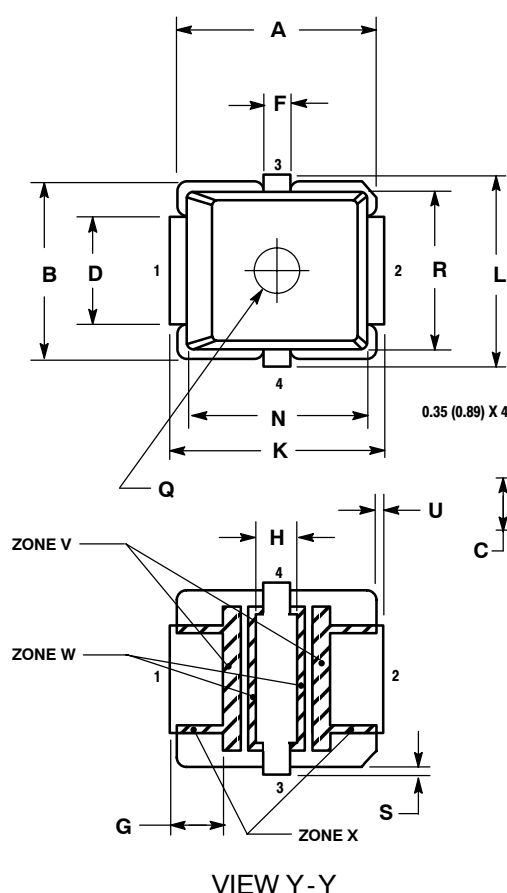
Table 6. Class AB Common Source S-Parameters at $V_{DS} = 12 \text{ Vdc}$, $I_{DQ} = 50 \text{ mA}$ (continued)

| f GHz | S_{11} | | S_{21} | | S_{12} | | S_{22} | |
|----------|------------|---------------|------------|---------------|------------|---------------|------------|---------------|
| | $ S_{11} $ | $\angle \phi$ | $ S_{21} $ | $\angle \phi$ | $ S_{12} $ | $\angle \phi$ | $ S_{22} $ | $\angle \phi$ |
| 2.85 | 0.868 | 136.03 | 1.845 | 7.80 | 0.043 | -38.56 | 0.537 | 153.86 |
| 2.90 | 0.866 | 134.67 | 1.828 | 6.20 | 0.043 | -39.94 | 0.536 | 153.32 |
| 2.95 | 0.866 | 133.02 | 1.812 | 4.39 | 0.043 | -41.41 | 0.534 | 152.08 |
| 3.00 | 0.868 | 131.47 | 1.795 | 2.53 | 0.043 | -42.49 | 0.536 | 151.08 |
| 3.05 | 0.865 | 129.99 | 1.780 | 0.80 | 0.043 | -43.57 | 0.535 | 150.49 |
| 3.10 | 0.864 | 128.11 | 1.766 | -1.00 | 0.043 | -44.68 | 0.532 | 149.20 |
| 3.15 | 0.865 | 126.39 | 1.745 | -2.87 | 0.043 | -45.67 | 0.533 | 148.09 |
| 3.20 | 0.864 | 124.86 | 1.728 | -4.58 | 0.043 | -46.62 | 0.533 | 147.42 |
| 3.25 | 0.861 | 122.97 | 1.714 | -6.48 | 0.043 | -47.78 | 0.531 | 146.29 |
| 3.30 | 0.863 | 121.30 | 1.697 | -8.33 | 0.043 | -49.02 | 0.532 | 145.13 |
| 3.35 | 0.862 | 119.77 | 1.681 | -9.97 | 0.043 | -49.91 | 0.532 | 144.52 |
| 3.40 | 0.860 | 117.84 | 1.665 | -11.83 | 0.043 | -50.93 | 0.529 | 143.46 |
| 3.45 | 0.862 | 116.26 | 1.648 | -13.70 | 0.043 | -51.73 | 0.529 | 142.35 |
| 3.50 | 0.861 | 114.65 | 1.630 | -15.43 | 0.043 | -52.55 | 0.530 | 141.50 |
| 3.55 | 0.860 | 112.77 | 1.620 | -17.24 | 0.044 | -53.64 | 0.527 | 140.51 |
| 3.60 | 0.862 | 111.19 | 1.602 | -18.99 | 0.044 | -54.74 | 0.525 | 139.19 |
| 3.65 | 0.861 | 109.76 | 1.584 | -20.65 | 0.044 | -55.56 | 0.525 | 138.23 |
| 3.70 | 0.860 | 108.08 | 1.572 | -22.49 | 0.044 | -56.84 | 0.524 | 137.30 |
| 3.75 | 0.861 | 106.70 | 1.557 | -24.18 | 0.044 | -58.11 | 0.523 | 136.00 |
| 3.80 | 0.862 | 105.31 | 1.544 | -25.86 | 0.044 | -59.31 | 0.524 | 134.95 |
| 3.85 | 0.862 | 103.85 | 1.533 | -27.47 | 0.044 | -60.49 | 0.523 | 134.13 |
| 3.90 | 0.861 | 102.50 | 1.519 | -29.14 | 0.044 | -61.50 | 0.521 | 132.71 |
| 3.95 | 0.862 | 101.16 | 1.508 | -30.97 | 0.044 | -62.41 | 0.522 | 131.61 |
| 4.00 | 0.861 | 99.84 | 1.499 | -32.49 | 0.044 | -63.14 | 0.520 | 130.97 |
| 4.05 | 0.861 | 98.44 | 1.494 | -34.26 | 0.044 | -64.07 | 0.518 | 129.57 |
| 4.10 | 0.861 | 97.12 | 1.482 | -35.96 | 0.044 | -64.91 | 0.518 | 128.23 |
| 4.15 | 0.859 | 96.07 | 1.474 | -37.51 | 0.045 | -65.77 | 0.515 | 127.49 |
| 4.20 | 0.858 | 94.61 | 1.471 | -39.42 | 0.045 | -67.06 | 0.512 | 125.93 |
| 4.25 | 0.859 | 93.26 | 1.463 | -41.19 | 0.045 | -68.21 | 0.512 | 124.32 |
| 4.30 | 0.859 | 92.06 | 1.458 | -42.86 | 0.045 | -69.40 | 0.511 | 123.47 |
| 4.35 | 0.857 | 90.72 | 1.457 | -44.58 | 0.046 | -70.54 | 0.507 | 122.03 |
| 4.40 | 0.857 | 89.22 | 1.450 | -46.51 | 0.046 | -71.95 | 0.508 | 120.25 |
| 4.45 | 0.855 | 87.99 | 1.446 | -48.27 | 0.046 | -73.34 | 0.508 | 119.27 |
| 4.50 | 0.855 | 86.49 | 1.453 | -50.09 | 0.047 | -74.58 | 0.504 | 117.72 |
| 4.55 | 0.855 | 84.61 | 1.448 | -52.14 | 0.046 | -75.92 | 0.503 | 115.65 |
| 4.60 | 0.854 | 83.10 | 1.449 | -53.98 | 0.047 | -76.82 | 0.501 | 114.46 |
| 4.65 | 0.853 | 81.10 | 1.454 | -56.16 | 0.047 | -78.14 | 0.495 | 112.83 |
| 4.70 | 0.851 | 78.94 | 1.450 | -58.44 | 0.048 | -79.84 | 0.492 | 110.59 |
| 4.75 | 0.851 | 77.09 | 1.450 | -60.56 | 0.048 | -81.55 | 0.491 | 109.01 |
| 4.80 | 0.848 | 74.85 | 1.450 | -62.75 | 0.048 | -83.28 | 0.486 | 107.24 |
| 4.85 | 0.849 | 72.60 | 1.448 | -65.03 | 0.048 | -84.88 | 0.483 | 105.01 |
| 4.90 | 0.845 | 70.48 | 1.443 | -67.33 | 0.048 | -86.30 | 0.482 | 103.27 |
| 4.95 | 0.841 | 68.09 | 1.443 | -69.60 | 0.048 | -87.72 | 0.477 | 101.51 |
| 5.00 | 0.841 | 65.50 | 1.442 | -72.12 | 0.048 | -89.22 | 0.474 | 99.28 |

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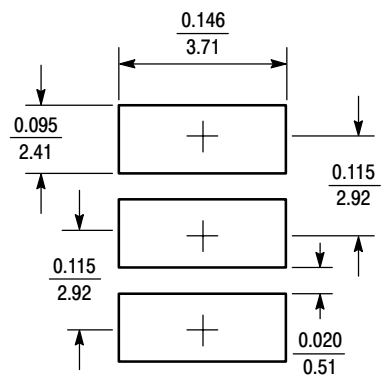
PACKAGE DIMENSIONS



- NOTES:
1. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1984.
 2. CONTROLLING DIMENSION: INCH
 3. RESIN BLEED/FLASH ALLOWABLE IN ZONE V, W, AND X.

- STYLE 1:
1. DRAIN
 2. GATE
 3. SOURCE
 4. SOURCE

**CASE 466-03
ISSUE D
PLD-1.5
PLASTIC**



(inches
mm)

SOLDER FOOTPRINT

| DIM | INCHES | | MILLIMETERS | |
|--------|--------|-------|-------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.255 | 0.265 | 6.48 | 6.73 |
| B | 0.225 | 0.235 | 5.72 | 5.97 |
| C | 0.065 | 0.072 | 1.65 | 1.83 |
| D | 0.130 | 0.150 | 3.30 | 3.81 |
| E | 0.021 | 0.026 | 0.53 | 0.66 |
| F | 0.026 | 0.044 | 0.66 | 1.12 |
| G | 0.050 | 0.070 | 1.27 | 1.78 |
| H | 0.045 | 0.063 | 1.14 | 1.60 |
| J | 0.160 | 0.180 | 4.06 | 4.57 |
| K | 0.273 | 0.285 | 6.93 | 7.24 |
| L | 0.245 | 0.255 | 6.22 | 6.48 |
| N | 0.230 | 0.240 | 5.84 | 6.10 |
| P | 0.000 | 0.008 | 0.00 | 0.20 |
| Q | 0.055 | 0.063 | 1.40 | 1.60 |
| R | 0.200 | 0.210 | 5.08 | 5.33 |
| S | 0.006 | 0.012 | 0.15 | 0.31 |
| U | 0.006 | 0.012 | 0.15 | 0.31 |
| ZONE V | 0.000 | 0.021 | 0.00 | 0.53 |
| ZONE W | 0.000 | 0.010 | 0.00 | 0.25 |
| ZONE X | 0.000 | 0.010 | 0.00 | 0.25 |

ARCHIVE INFORMATION

ARCHIVE INFORMATION

REVISION HISTORY

The following table summarizes revisions to this document.

| Revision | Date | Description |
|----------|-----------|--|
| 5 | Jan. 2008 | <ul style="list-style-type: none">Listed replacement part, p. 1Added Revision History, p. 9 |

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